NSN 5961-01-051-4014

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View Online at https://aerobasegroup.com/nsn/5961-01-051-4014 **Inclosure Material:** Plastic **Overall Length:** 0.106 inches **Overall Diameter:** 0.189 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 collector to base voltage, dc and 12.0 collector to emitter voltage, dc and 2.0 emitter to base voltage, dc **Power Rating Per Characteristic:** 180.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 28480-1854-0632 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: